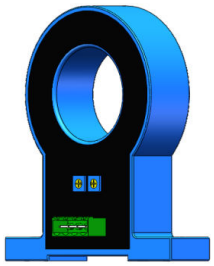
Hall effect Current Sensor

Q/SC 003 2010

SCK13



Product description

Features

- Based on Hall effect measurement principle, open loop circuit mode.
- The isolation voltage between primary and secondary is greater than 3000VAC.
- Comply with UL94-V0 flame retardant rating.

Performance

- It can measure DC, AC, pulse, and various irregular waveform currents of cable conductors under isolation conditions.
- Wide measurement range, fast response speed, low zero drift, low temperature drift, high accuracy and good linearity.
- Dynamic performance (di/dt and response time) is optimal when the busbar is fully filled with primary perforations.
- Strong ability to resist external electromagnetic interference (BCI, EFT, CS, CE, ESD, dv/dt, etc.).

Application

- It can be widely used in inverters, UPS, photovoltaic inverters, electric vehicle drives, high-frequency power supplies, inverter welding machines and other products.

Implementation standards

- GB/T 7665-2005
- JB/T 7490-2007
- JB/T 25480-2010
- JB/T 9473-2020
- SJ 20792-2000

Certification

Technical Parameters

Model / Parameters（25℃）	SCK13T-						
	200A	300A	500A	800A	1000A	1500A	2000A
Primary Current (A)I_{PN}	200A	300A	500A	800A	1000A	1500A	2000A
Primary Current Max. Peak Value (A) I_{PM}	±600A	±900A	±1500A	±2400A	±2400A	±2400A	±2400A
Output voltage (V) V_{out} @±I_{PN}, R_L=10KΩ	±4V±1%						

Electrical Data

Item	Min.	Typical	Max.	Unit
Input power supply voltage range Vc （±5%）（Remark 1，Remark 2）	±11	±15	±18	V_{DC}
Current consumption Ic	-	±15	±20	mA
Withstand resistance R_{INS} @500V DC	1000	-	-	MΩ
Output voltage Vout @I_{PN}, R_L=10KΩ，T_A= 25℃	3.960	4.000	4.040	V
Output internal resistance R_{OUT}	-	102	-	Ω
Load Resistance R_L（Remark 3）	1	10	-	KΩ
Accuracy X @I_{PN}，T_A= 25℃	-	±1	-	%
Linearity ε_L @R_L=10KΩ，T_A= 25℃	-	±0.5	-	%I_{PN}
Offset voltage V_{OE} @T_A= 25℃	-	±10	±20	mV
Hysteresis voltage V_{OM} @ I_{PN}→0	-	±10	±20	mV
Temperature Coefficient of Offset Voltage TCV_{OE}	-	±0.5	±1	mV/℃
Output voltage temperature coefficient TCV_{out}	-	±0.05	±0.1	%/℃
Response time t_D @ 0→I_{PN}	-	3	5	us
Ambient operating temperature T_A	-40	25	125	℃
Ambient storage temperature T_s	-40	25	125	℃
Withstand voltage V_D@50Hz,60s,0.1mA		3000		V_{AC}
Weight m		230		g

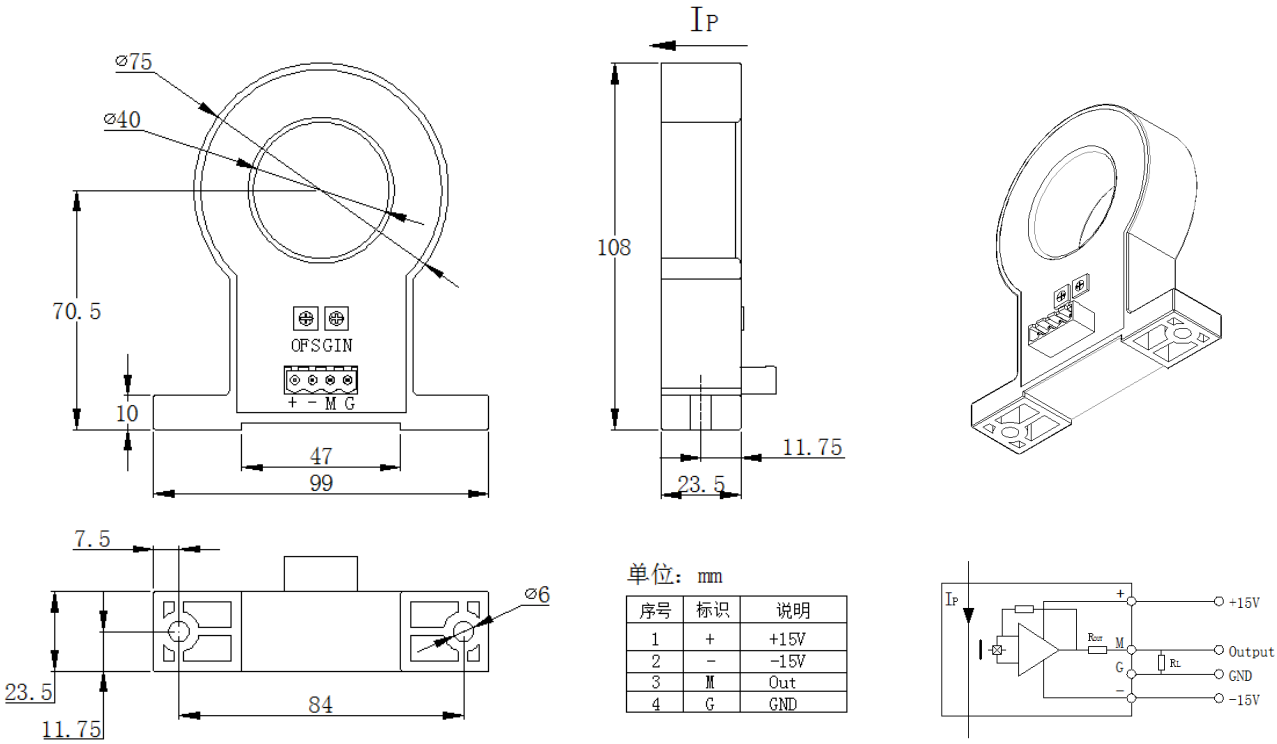
Remarks:

1. VC is less than the minimum value, which will lead to inaccurate measurement, VC is greater than the maximum value, which may cause permanent failure of the measurement device.
2. When ± 12V<VC<±15V, the measurement range will be reduced.

3. $V_{OUT} = 4.04 * \frac{R_L}{102 + R_L} * \frac{I_P}{I_{PN}} + V_{OE}$

4. Follow the speed di/dt>50A/uS

Dimensions (in mm)



单位：mm

序号	标识	说明
1	+	+15V
2	-	-15V
3	M	Out
4	G	GND

Notes:

1. Size error: ±1mm;
2. Primary aperture: φ40mm;
3. Fastening hole: φ6mm*2;
4. Output terminal: 2EDGVC-5.08-4P;
Mating plug: 2EDGK-5.08-4P;
5. The IP indication direction is the positive direction of the current, OFS is the zero adjustment, and GIN is the output regulation;
6. The temperature of the primary conductor shall not exceed 105°C;
7. Incorrect wiring may cause damage to the sensor.